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DEFENSE INDUSTRIAL BASE ASSESSMENT: THE U.S. INTEGRATED CIRCUIT DESIGN AND MANUFACTURING INDUSTRY



SCOPE OF ASSESSMENT

The U.S. Department of Commerce, Bureau of Industry and Security (BIS), Office of Technology Evaluation (OTE), is conducting a survey and assessment of the health and competitiveness of the U.S. design and manufacturing infrastructure available for producing Integrated Circuit products required for meeting U.S. national security needs. The goal of this study is to provide decision makers in the U.S. Departments of Defense, Energy, Justice, Homeland Security, and other Executive Branch agencies with detailed information on (1) the health and status of Integrated Circuit design and manufacturing capabilities remaining in the United States; and (2) the outlook for maintaining these activities in the future. The scope of this effort encompasses Integrated Circuit design and manufacturing resources, including the supply chain.

RESPONSE TO THIS SURVEY IS REQUIRED BY LAW

A response to this survey is required by law (50 U.S.C. App. Sec. 2155). Failure to respond can result in a maximum fine of \$10,000, imprisonment of up to one year, or both. Information furnished herewith is deemed confidential and will not be published or disclosed except in accordance with Section 705 of the Defense Production Act of 1950, as amended (50 U.S.C App. Sec. 2155). Section 705 prohibits the publication or disclosure of this information unless the President determines that its withholding is contrary to the national defense. Information will not be shared with any non-government entity, other than in aggregate form. The information will be protected pursuant to the appropriate exemptions from disclosure under the Freedom of Information Act (FOIA), should it be the subject of a FOIA request.

Notwithstanding any other provision of law, no person is required to respond to nor shall a person be subject to a penalty for failure to comply with a collection of information subject to the requirements of the Paperwork Reduction Act unless that collection of information displays a currently valid OMB Control Number.

BURDEN ESTIMATE AND REQUEST FOR COMMENT

Public reporting burden for this collection of information is estimated to average 14 hours per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information to BIS Information Collection Officer, Room 6883, Bureau of Industry and Security, U.S. Department of Commerce, Washington, D.C. 20230, and to the Office of Management and Budget, Paperwork Reduction Project (OMB Control No. TKTK-TKTK), Washington, D.C. 20503.

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Section I	: General Instructions
	Your organization is required to complete this survey of the U.S. Integrated Circuit industry using an Excel template, which can be downloaded from the BIS website: http://bis.doc.gov/chipsurvey
A.	If you are not able to download the survey document, at your request BIS, staff will e-mail the Excel survey template directly to you.
	For your convenience, a PDF version of the survey and required drop-down content is available on the BIS website to aid internal data collection. DO NOT SUBMIT the PDF version of the survey as your response to BIS. Should this occur, your organization will be required to resubmit the survey in the requested Excel format.
	Respond to every question. Surveys that are not fully completed will be returned for completion. Use the comment boxes to provide any information to supplement responses provided in the survey form. Make sure to record a complete answer in the cell provided, even if the cell does not appear to expand to fit all the information.
B.	DO NOT CUT AND PASTE RESPONSES WITHIN THIS SURVEY. Survey inputs should be completed by typing in responses or by use of a drop-down menu. The use of cut and paste can corrupt the survey template. If your survey response is corrupted as a result of cut and paste responses, a new survey will be sent to your organization for immediate completion.
C.	Do not disclose any classified information in this survey form.
D.	Estimates are sometimes acceptable where indicated, but in sections that do not explicitly allow estimates you must contact BIS survey support staff before including estimates.
E.	Upon completion of the survey, final review, and certification, transmit the survey document via e-mail to: chipstudy@bis.doc.gov
F.	Questions related to the survey should be directed to BIS survey support staff at chipstudy@bis.doc.gov (E-mail is the preferred method of contact).
1.	You may also speak with a member of the BIS survey support staff by calling (202) 482-6339
	For questions related to the overall scope of this Industrial Base assessment, contact:
G.	Brad Botwin, Director, Industrial Studies Office of Technology Evaluation, Room 1093 U.S. Department of Commerce 1401 Constitution Avenue, NW Washington, DC 20230
	DO NOT submit completed surveys to Mr. Botwin's postal or e-mail address; all surveys must be submitted electronically to XXX
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Section II: Definitions		
Term	Definition	
Applied Research	Systematic study to gain knowledge or understanding necessary to determine the means by which a recognize and specific need may be met. This activity includes work leading to the production of useful materials, devices and systems or methods, including design, development, and improvement of prototypes and new processes.	
Authorizing Official	Executive officer of the organization or business unit or other individual who has the authority to execute this survey on behalf of the organization.	
Basic Research	Systematic, scientific study directed toward greater knowledge or understanding of the fundamental aspects of phenomena and of observable facts.	•
Capability	The ability to perform defined design and/or manufacturing steps for producing integrated circuit products within organization's own facilities and with its own employees with little or no outsourcing.	n an
Capital Expenditures	Investments made by an organization in buildings, equipment, property, and systems where the expense is depreciated. This does not include expenditures for consumable materials, other operating expenses and sala associated with normal business operations.	ıries
Commercial and Government Entity (CAGE) Code	Commercial and Government Entity (CAGE) Code identifies companies doing or seeking to do business with the U.S. Federal Government. The code is used to support mechanized government systems and provides a standardized method of identifying a given facility at a specific location. Find CAGE codes at https://cage.dla.mil/search/ .	he
Commercially Sensitive Information (CSI)	Privileged or proprietary information which, if compromised through alteration, corruption, loss, misuse, or unauthorized disclosure, could cause serious harm to the information's owners.	
Customer	An entity to which an organization directly delivers the product or service that the facility produces. A customer be another organization or another facility owned by the same parent organization. The customer may be the cuser for the item but often will be an intermediate link in the supply chain, adding additional value before transferring the item to yet another customer.	
Cyber Security	The body of technologies, processes, and practices designed to protect networks, computers, programs, and d from attack, damage, or unauthorized access.	lata
Data Universal Numbering System (DUNS)	A nine-digit numbering system that uniquely identifies an individual business. Find DUNS numbers at http://fedgov.dnb.com/webform .	
Development	The design, development, simulation, or experimental testing of prototype or experimental hardware or systems validate technological feasibility or concept of operation, to reduce technological risk, or to provide test systems prior to production approval.	
Design	Design activity required to implement a product concept in support of the manufacture of the Integrated Circuit product at a fabrication facility.	
Facility	A facility can constitute a single building or multiple buildings functioning as a unified design, fabrication, or packaging facility. Design, fabrication, and packing, test and assembly operations must be identified separately Individual wafer fabrication facilities serving distinct sets of technology nodes should be identified separately evoperating on a single campus.	
Full Time Equivalent (FTE) Employees	Employees who work for 40 hours in a normal work week. Convert part-time employees into "full time equivale by taking their work hours as a fraction of 40 hours.	ents"
Harmonized Tariff Schedule (HTS)	The Harmonized Tariff Schedule (HTS) is the statute used to determine tariff classifications for goods imported the United States and maintained and published by the United States International Trade Commission. The HT based on the International Harmonized System.	
Integrated Circuit	Analog or digital devices that incorporate transistors, diodes, capacitors, resistors, and other circuit elements the are integrated on a single substrate (chip), typically silicon.	nat
Location	For the purpose of this survey, a location is a single contiguous site.	
Manufacturing	The production of a working Integrated Circuit product in a fabrication facility.	
Neutron Hardened	Integrated Circuit products incorporating design features and/or physical characteristics that can withstand the damaging effects of high-speed neutrons, gamma rays, and electromagnetic pulses that accompany a nuclear weapons detonation. Most CMOS[1] technologies are inherently neutron hardened without any specific effort o the part of an ICs designer/manufacturer. For "minority carrier" IC devices that are affected by neutron-induced displacement damage, a level of 1X1014 n/cm2 (1MeV equivalent fluence) is the accepted standard.[2]	n
North American Industry Classification System (NAICS) Code	North American Industry Classification System (NAICS) codes identify the category of product(s) or service(s) provided by an organization. Find NAICS codes at http://www.census.gov/epcd/www/naics.html	
Organization	A company, firm, laboratory, or other entity that owns or controls one or more U.S. establishment capable of designing and/or manufacturing Integrated Circuit products. A company may be an individual proprietorship, partnership, joint venture, or corporation (including any subsidiary corporation in which more than 50 percent of outstanding voting stock is owned by a business trust, cooperative, trustee(s) in bankruptcy, or receiver(s) undedecree of any court owning or controlling one or more establishment.	
Product/Process Development	Conceptualization and development of a product prior to the production of the product for customers.	
Radiation Hardened	Integrated Circuit products incorporating design features and/or physical characteristics that demonstrate a capability to resist radiation-induced damage from industrial sources, electromagnetic pulses, weapons system and/or charged particles in space that can damage circuitry and render a device inoperable. Some IC devices be considered radiation hardened when their total dose failure level exceeds >300 krad.[3] A total dose failure of 500krad is the standard cited in International Traffic in Arms (ITAR) regulations.[4]	may

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Radiation Tolerant	Integrated Circuit products incorporating design features and/or physical characteristics with limited capability to resist radiation induced damage from industrial sources, electromagnetic pulses, industrial sources, weapons systems, and charged particles in space that can damage circuitry and render a device inoperable. Radiation tolerant would cover parts having a total dose failure level >100 krad but less than 300 krad.
Research and Development	Basic and applied research in the engineering sciences, as well as design and development of prototype products and processes.
Semiconductor	Elemental materials such as silicon and germanium (or compounds like gallium arsenide) that possess levels of electrical conductivity that are less than a conductor but greater than an insulator. The properties of these materials and similar ones can be manipulated to affect conductivity through temperature and/or the use of dopants.
Service	An intangible product (contrasted to a good, which is a tangible product). Services typically cannot be stored or transported, are instantly perishable, and come into existence at the time they are bought and consumed.
Single-Event Effects Resistant	Single-event effects caused by a single energetic particle striking an Integrated Circuit (IC) device. Performance of the IC device is not compromised to a point where it is inoperable or not reliable for executing a mission as a result of latch-up, burnout, or gate rupture.
Single Source	An organization that is designated as the only accepted source for the supply of parts, components, materials, or services, even though other sources with equivalent technical know-how and production capability may exist.
Sole Source	An organization that is the only source for the supply of parts, components, materials, or services. No alternative U.S. or non-U.S. based suppliers exist other than the current supplier.
Supplier	An entity from which your organization obtains inputs. A supplier may be another firm with which you have a contractual relationship, or it may be another facility owned by the same parent organization. The inputs may be goods or services.
Trusted Access Program	A program implemented by the National Security Agency and the Defense Microelectronics Activity (DMEA) to qualify Integrated Circuit design and manufacturing companies as "trusted" suppliers of application specific Integrated Circuit (ASIC) products required for national security applications.
United States	The "United States" or "U.S." includes the 50 states, Puerto Rico, the District of Columbia, the island of Guam, the Trust Territories, and the U.S. Virgin Islands.
Wafer Starts Per Week	The number of semiconductor wafers that can be processed by an Integrated Circuit production line(s) in a 7-day period.
	[1] Complimentary metal oxide semiconductor (CMOS) is a class of semiconductor used in digital logic circuits employed in microcontrollers, microprocessors, memory, and other devices. The technology also is used in analog circuits in sensors, transceivers, data converters and other systems.
	[2] Sandia National Laboratories. A minority carrier device is a device in which current is conducted by charge carriers of sign (positive or negative) opposite to the dopant polarity of the underlying semiconductor material. In other words, current carried by electrons (negative) in a p-type semiconductor, or by holes in an n-type semiconductor. In semiconductors, minority charge carriers are less abundant than majority charge carriers. Minority carrier devices: Bipolar junction transistors, charge-coupled devices (CCDs), solar cells.
	[3] Sandia National Laboratories.
	[4] ITAR Part 121 – The United States Munitions List (See www.pmddtc.state.gov/consolidated_itar.htm. [Microelectronic circuits are considered radiation hardened when they exceed all five of these standards: (1) Total dose of 5x105 Rads (Si); (2) Dose rate upset of 5x108 Rads (Si) per second; (3) Neutron dose of 1x1014 N/cm2; (4) Single-Event upset of 1x10minus;7 or less error/bit/day; and (5) Single-Event latch-up free and having a dose rate latch-up of 5x108 Rads (Si) per second or greater.]
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CORPORATE LEVEL RESPONSE

Section III: Organization Reporting Profile

This survey consists of sections that must be answered at the Corporate Level and other sections that must be answered at the Facility Level. The reporting level will be specified at the top of each section in RED. Facilities that will be responding separately from their corporate headquarters should proceed to section 1a to begin the survey.

from their o	corporate neadquarte	ers snould proceed	to section ratio beg	in the survey.								
		De	escription of Busin	ess Activity								
	Select the description its business:	on of your organizati	on's U.S. operation	s that that most close	ely reflects							
	Design Integrated C	ircuit products (fable	ess)			Yes/No						
	Design and Manufa	cture Integrated Circ	cuit products (integr	ated device manufac	cturer)							
	Design and Manufa	cture Integrated Circ	cuit products; and p	erform Package, Tes	st & Assembly							
A.	Manufacture Integra	ated Circuit products	(as a foundry)									
	Manufacture Integra	ated Circuit products	(as a foundry) and	perform Package, T	est & Assembly							
	Design Integrated C	ircuit products (fable	ess); and perform F	ackage, Test & Asse	embly							
	Provide Package, T	est & Assembly Ser	vices									
	Other [Write In]											
	Identify the number	of Integrated	IC A	ctivity	U.S. Locations	Non-U.S. Locations						
	Circuit-related desigmanufacturing facilit	n and	Design									
B.	organization operate States in 2016.		Manufacturing									
			Packaging, Test & Assembly									
	Comn	nents:										
	Identify all of your o the United States.	rganization's Integra	ated Circuit-related	Design, Manufacturir	ng, and Packaging fa	cilities* located in						
	Facility* Name	City	State	DMEA Certified Trusted** Facility	-	y Scope Vork						
				Yes	Design							
				No	Manufacturing							
					PT&A							
					Other							
•												
C.												
	and packing, test and as nodes should be identifie	sembly operations must ed separately even if ope	be identified separately. rating on a single camp		on facilities serving distin	ct sets of technology						
	Circuit products.	tification from the Defens	se Microelectronics Activ	rity's Trusted Accredidatio	n Program to design or m	nanufacture Integrated						
C	Comments:	ESS CONFIDENTIA	I - Por Soction 70	5(d) of the Defense	Production Act							
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		C	ORPORATE LEVEL RESP	PONSE		
Section III:	: Reporting Level (Cont.)					
A.	Is your organization publicly traded	or privately held?		If your organization is its stock ticker symbol	publicly traded, identify l.	
	Provide the following identification	codes, as applicable, f	for your organization.			
B.	Data Universal Numbering System (DUNS) Code(s)		Harmonized Tariff Schedule (HTS) Code(s)		NAICS (6-digit) Code(s)*	
	Find DUNS numbers at:		Find HTS numbers at:		Find NAICS codes at:	
	http://fedgov.dnb.com/w ebform		http://hts.usitc.gov		http://www.census.gov/epcd/www/naics.html	
	Indicate if your organization qualifie					
	A small business enterprise (as de	•	,			
	8(a) Firm (as defined by the Small		on)			
C.	A historically underutilized busines	s zone (HUB Zone)				
	A minority-owned business					
	A woman-owned business					
	A veteran-owned or service-disable					
	Specify the industry sectors that you located in the United States:	ur organization serves	s through the provision of de	esign and/or manufactu	uring services for Integrate	d Circuit products
	Aviation systems/Avionics	Yes	Healthcare/Medical Devic	es		
D.	Automotive	No	Industrial			
D.	Consumer electronics	N/A	Military and Space			
	Communications		Other National Security sy	ystems		
	Electronic Data Processing		Optical/Photonics			
	Energy		Other [Write In]			
	Comments:					
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		FACILIT	Y LEVEL RESPON	SE					
	a: Organization Information								
	y consists of sections that must be answered at the Corpo	ate Level and other	er sections that mus	st be answered at the	e Facility Level. The reporting level will be	e specified at the			
top of each	section as appropriate.								
	Provide the following information for your facility.								
	Facility Name								
	Street Address								
	City								
A.	State								
	Zip Code								
	Website								
	Phone Number								
	CAGE Code (if applicable)								
		Driman	/ Business	Integrated circuit/semico	nductor product design facility				
		•	/ Dusiness	Integrated circuit/semico	onductor product fabrication facility				
В.	Select the option that most closely describes this facility's Primary Business, and indicate any "Additional Business		Business Line	Integrated circuit/semico	onductor product packaging, assembly, and test facility				
В.	Lines."	Additional	Dusiness Line	Integrated circuit/semico	nductor product research and development facility				
		Additional	Business Line	Integrated circuit/semico	nductor product corporate headquarters facility				
		Additional	Dusiness Line	N/A					
	Provide the following information for your parent organiza	tion(s), if applicab	le. Enter N/A if no p	arent organization.					
			Parent Organizatio	n 1	Parent Organization 2	2			
	Organization Name								
C.	Street Address								
C.	City								
	State/Province								
	Country								
	Postal Code/Zip Code								
	Point of Contact regarding this survey:								
D.	Name	Title	Phone	Number	E-mail Address	State			
	Comments:								
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Next Page Integrated Circuit Design & Manufacturing 2.a List this facility's Integrated Circuit Design and Manufacturing product capabilities and market types in the United States in calendar year 2016. Design and Manufacturing Facility Market Types and Capabilities Conventional Integrated Circuit Products **Product Capabilities** Single-Event Effects Resistant Radiation Hardened **Neutron Hardened** Market Types Design/Manufacture/Both/Neither 2.b Identify this facility's Integrated Circuit-related design and manufacturing capabilities by technology node, wafer size, and material type Capability to Design and/or Manufacture - by Technology Node, Wafer Size & Material Type (Select all that apply -- A blank response is counted as "No Capability") Technology Node -- by Wafer Carbon Based Technologies (e. nanotubes) Aluminum (Arsenide Capability [nanometers] 2- or 3-inch 4-inch esign - Radiation Resistant 6-inch Manufacture - Conventional 8-inch 12-inch Both - Design Comments:

tote: 10,000 nanometers equals 10 micrometers 'Respond to this specification if your organization expects to develop a capability to work at this Technology Node by 2021.

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								CORPORA	TE LEVEL F	RESPONSE										
Section 2 Integral 2.c Specify your organization's design and specification in the section 2.c. Integral 2.c. Specify your organization's design and specification in the section 2.c. Integral 2.c. Specify your organization in the section 2.c. Specify your organization 2.c. Specify your organization 2.c. Specify your organization 3.c. Specify your organization 3.	rated Circuit ign and manu					o the produc	tion of custo	m radiation-t	olerant, radia	ation-harden	ed, and neu	ron hardene	d Integrated	Circuit prod	ucts located	in the United	States:			
								Canability	to Dooign o	nd/or Monus	facture by	Davisa 9 M	eterial Type							
											facture - by ponse is cour									
Device Type	Conventiona IC Products	Radiation Tolerant	Radiation Hardened	Neutron Hardened	Single-Event Effects Resistant - Destructive	Single-Event Effects Resistant - Non-Destructive	Amorphous Silicon	Bulk Silicon	Silicon on Insulator	Silicon Germanium	Silicon on Sapphire	Silicon Carbide	Aluminum Gallium Arsenide	Gallium Arsenide	Gallium Nitride	Indium Phosphate	Antimonides	Organic Technologies	Carbon Based Technologies (e.g., nanotubes)	Superconducting Materials
Analog/Linear Technologies	Design																			ĺ
Digital Logic Technologies	Manufacture																			1
Digital Signal Processors	Both																			
Field Programmable Gate Arrays	Neither																			
One-time, Electrically Programmable Gate Arrays																				
Mask Programmable Gate Arrays																				1
Structured ASICs [a.k.a. Structured Arrays; Platform ASICs]																				
Standard Cell ASICs [a.k.a. cell-based ASICs]																				
Custom ASICs																				
MMIC** Technologies																				<u></u>
Mixed Signal Technologies																				<u></u>
Processors																				<u></u>
Nonvolatile Memory																				
3-D Nonvolatile Memory																				<u></u>
SRAM																				<u></u>
DRAM - DDR3																				<u></u>
DRAM - DDR4																				<u></u>
IR*-Focal Plane Arrays																				<u> </u>
Anti-Tamper Technology																				<u></u>
Display Electronics																				<u></u>
MEMS Technologies																				<u></u>
Optical/Photonic Technologies																				
RF Technologies																				
Other: [Write In]																				
Comments:	mments:																			
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*Nonvolatile random access memory that can be erased electronically and rewritten up to 100,000 times.

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^{**} A non-volatile memory technology that can change its resistance in varying levels. It can offer resistance in two states for a digital 0 or 1 or to levels in between to go beyond a binary system.

***Pico second = 1 trillionith of a second.

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Continuo Ded Talament Des	l I I a mala manad	Maurinan I	landanad IC			LEVEL RE	SPONSE								
Section 3 Rad Tolerant, Rad 3.a Identify your organization's current of							n design m	anufacturin	a or both for	each of the	following ty	nes of Integr	ated Circuit		
3.a Identity your organization's current	Japaniilies,	previous ce	ipabilities art	u iiiterest iii	developing	capabilities	ii desigii, iii	anulaciumi	y or bour for	each of the	ionowing ty	pes of integra	ateu Oircuit.		
			Curre	ntly (in 201	7) has				Interes	sted in dev	eloning car	pabilities for	U.S. Gove	rnment	
Type of Integrated C	ircuit			apabilities		Had cap	pabilities 20	13-2016				•			
										nstituting Ca	apacity	1	tiating Capa	city	
Radiation Tolerant			Design			Design			Design			Design			
Radiation Hardened			Manufacture			Manufacture			Manufacture			Manufacture			
Neutron Hardened			Both			Both			Both			Both			
Single-Events Effects Resistant - Destru			Neither			Neither			Neither			Neither			
Single-Event Effects Resistant - Nondes Does your organization design or manuf Resistant Integrated Circuits?		ation Tolera	ant, Radiation	Hardened,	Neutron Ha	irdened or S	ingle-Event	Effects		Yes/No		If no, proceed to Section 4.			
3.b Identify your organization's capabilit	ies to design	n and/or ma	anufacture cu	stom Integr	ated Circuit	products tha	t are Radiat	ion Toleran	t, Radiation I	Hardened, N	leutron Har	dened or Sin	gle-Event Ef	fects	
Resistant at locations in the United State	es.														
					Capab	ility to Desi	gn and/or N	lanufacture	e - by Materi	al Type					
					(Select	all that apply	A blank resp	onse is coun	ted as "No cap	pability")					
							Ē						(e.g.,	D	
							Aluminum Gallium Arsenide					ω	pa s (e	Superconducting Materials	
	Amorphous Silicon	u o	⊊ .	Silicon Germanium	⊊ n		E			ate	Antimonides	Organic Technologies	Carbon Based Technologies (nanotubes)	npu s	
	n rb	iii o	ator	nan	o no	r ge	nin	E pic	E a	m gydg	- Lo	in in	a du du	aroo rial	
	o iii	Bulk Silicon	Silicon on Insulator	Sem Sem	Silicon on Sapphire	Silicon Carbide	Aluminum Arsenide	Gallium Arsenide	Gallium Nitride	Indium Phosphate	iţi.	Prga ech	Sarb ech ano	Supe	
	4 0	ш	0) =	0, 0	0, 0,	0,0	4.4	0	02		,	O F	OFL	0) 2	
Radiation Tolerant	Design														
	Manufacture														
Radiation Hardened															
Neutron Hardened	Both														
Single-Event Effects Resistant Destructive	Neither														
Single-Event Effects Resistant - Non-Destructive															
						-4		-1-104 - 4	-:-+				in - d \ f=		
Radiation Tolerant: Integrated circuit prindustrial sources, electromagnetic pulse											i induced da	amage (ioniz	ing dose) iro	om	
Radiation Hardened: Integrated circuit	products inc	corporating	design featur	es and/or p	hysical char	acteristics th	at demonstr	rate a capal	oility to resist	effects from	radiation-i	nduced dama	age (ionizing	dose)	
from industrial sources, electromagnetic														,,	
	<u> </u>														
Neutron Hardened: Integrated circuit por electromagnetic pulses that accompany				s and/or phy	ysical charad	cteristics tha	t can withsta	and the dam	naging effects	s of high-spe	eed neutron	s, gamma ra	ys, and		
Single-Event Effects (SEE) Resistant	- Destructiv	e: Resistan	nt to effects ca	aused by a	single energ	etic particle	striking an li	ntegrated C	ircuit (IC) de	vice. Perfori	mance of th	e IC device i	s not compri	omised to	
a point where it is inoperable or not relia (LET) of 80 MeV.cm2/mg.]	ble for exec	uting a miss	sion as a resi	ult of event	latch-up, bui	rnout, or gate	e rupture, or	snapback.	[Immune to d	destructive S	SEEs up to	an ion linear	energy trans	sfer	
Single-Event Effects Resistant - Non-															
point where it is inoperable or not reliabl	e for execut	ing a missio	on as a result	or event up	set, transier	nt, or function	nai interrupt.	. [immune to	non-aestru	CTIVE SEES	s at an LE I	or 30-40 Me	v.cm 2/mg.]		
*Organization possesses manufacturing	process ted	chnology to	achieve radia	ation tolerar	nce, hardenii	ng, or neutro	n hardening	J.							
Comments:															

Manufacturing Capabilities & Production Rates Does your organization manufacture Integrated Circuits? Yes/No [If no, proceed to section 4c] As 1) State the average manufacturing capacity utilization rates at your U.S. -based fabrication facility for the years 2013-2016. Then, 2) state the maximum number of wafer starts possible per week at your manufacturing facility, 3) state the actual average wafer starts per week at your facility, and 4) indicate whether this facility will be operating through 2021. Average Manufacturing Capacity Utilization Rates Will this Facility Operate Through 2021? 2016 Average Actual Wafer Starts Per Week 2013 2014 2015 2016 Yes/No Normalized to 8-inch wafer equivalents.

"Assumes 7-days-a-week operations.

Note: a 100% utilization rate equals full operation with no downtime beyond that necessary for maintenance

4.b Specify the maximum Wafer Start capacity per week of your facility in 2016 in the United States by technology node, wafer size, and material type. Wafer Starts Per Week by Circuit Technology Node, Wafer Size & Material Type (State your wafer-start-per-week capacity -- A blank response is counted as "No capability") Minimum -- by Wafer Carbon Based Technology Node Capability Silicon Germanit Size [nanometers] 2- or 3-inch Write In # 10,000 6-inch 8-inch Comments Note: 10,000 nanometers equals 10 micrometers "Respond to this specification if your organization expects to develop a capability to work at this Technology Node by 2021.

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							<u>Ta</u>	ble of Conte	ents								Next Pag
							FACIL	ITY LEVEL	RESPONS	E							
Section 4	N	lask Produ	ction and C	apability													
Does your organ	nization curre	ently have ca	ptive, in-ho	use Integrate	ed Circuit ma	ask-making	capability?		Ye	s/No	[If no, proce	eed to secti	on 5]				
4.c Identify all te facilities sited at n	٠,		er ranges) fo	or which your	organization	is capable of	f producing n	nasks at com	pany-owned	and operate	d facilities loc	cated in 1) th	ne United Sta	ates; and 2)	in company	-owned and	operated
							Mask Tech	nology No	de (Nanom	eters)							
					(Sel	ect all that a	apply A bl	ank respons	se is counte	ed as "No Ca	apability")						
Location	10000 - 6000	<6000 - 3000	<3000 - 1500	<1000 - 800	<800 - 500	<500 - 350	<350 - 250	<250 - 180	<180-130	<130 - 90	<90 -65	<65 - 45	<45-32	<32-28	<22-14	<10-7	<7
2004	U.S.	Non-U.S.	Both														
Indicate the perce	entages of you	ur organizatio	n's Binary an	nd Phase-Shif	t mask produ	ction that are	a fulfillad in-h	ougo and by									
		Binary	Mask Blan	ks			e ruillileu iri-ri		external ma	sk makers.	Phase-	Shift Mask	Blanks				
What percent of y mask requiremen production perform	nts are fulfilled	ion's binary	Mask Blan In-H	ks louse	by Exter	nal Mask	What perce	nt of your org	anization's ments are		Phase- louse	-	Blanks rnal Mask kers				
	nts are fulfilled	ion's binary				nal Mask	What perce	nt of your org	anization's ments are			by Exter	rnal Mask				
mask requiremen	nts are fulfilled	ion's binary	In-H	louse	Mal	nal Mask kers	What perce phase-shift fulfilled by n	nt of your org	anization's ments are	In-H	louse	by Exter Ma	rnal Mask kers				
mask requiremen production perfori	nts are fulfilled	ion's binary	U.S.	Non-U.S.	U.S.	nal Mask kers Non-U.S.	What perce phase-shift fulfilled by n	nt of your org	anization's ments are	In-H U.S.	Non-U.S.	by Exter Ma U.S.	rnal Mask kers Non-U.S.				

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Section 5:	Performan	ce of Product	tion Stens – V	Wafer Processing 8		ORATE LEVEL RES	SPONSE					
Does your organization manufac			iioii Otopo		s/No	[If no, proceed to	section 6]					
Identify the Integrated Circuit was employs to perform wafer processi												ur organization
W. C. D			Non-U.S.	Country/Count	ries of Company-O	wned Facilities						
Wafer Processing and Pack	aging Steps	U.S.	Location	Country #1	Country #2	Country #3	Equipment Supplier #1	Equipment Supplier Country #1	Equipment Supplier #2 Name	Equipment Supplier Country #2	Equipment Supplier #3 Name	Equipment Supplier Country #3
Wafer Thinning												
Backgrinding		Yes/No	Yes/No									
Other [Write In]												
Wafer Dicing												
Saw Blade		Yes/No	Yes/No									
Laser Dicing												
Plasma Dicing												
Other [Write In]												
Interconnects												
Wired Bonding		Yes/No	Yes/No									
Solder Bumping												
Stud Bumping												
Pillar												
Redistribution Layer Connects												
Other [Write In]												
Circuit Bonding												
Direct Die Film (DDF) Attach		Yes/No	Yes/No									
Silver Glass Attach												
Leaded Solder Attach												
Gold Silicon Eutectic Attach												
Wafer-to-Wafer											1	
Other [Write In]												
Substrate/Packaging												
Ceramic		Yes/No	Yes/No									
Organic												
Through Silicon Via												
Flexible												

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Other [Write In]

Comments:

CORPORATE LEVEL RESPONSE

Section 6a: On-Die INPUT/OUTPUT Integrated Circuit Devices & Enabling Firmware

State the percentage of Integrated Circuit On-Die Input/Output Controllers and Firmware used by your organization in 2016 that were 1) produced internally at company facilities located in the U.S. and at Non-U.S. company locations; 2) licensed from U.S. companies, and 3) licensed from non-U.S. companies. Secondly, identify the top three non- U.S. suppliers and countries that were sources of these controllers and firmware used in products manufactured by your company in 2016. Select all that apply -- A blank response is counted as "No Capability."

Company Produced / Licensed	Non-U.S. Countries and Suppliers											
Type of On-die Hardware Protocol Controller & Firmware Controlled Device	Internally Produced at Company Locations in U.S.	Internally Produced at Company Locations Outside the U.S.	Licensed from U.S. Companies	Licensed from non- U.S. Companies	Total (must add up to 100%)	Supplier #1 Name	Country #1	Supplier #2 Name	Country #2	Supplier #3 Name	Country #3	
PCI Express - Controller	%	%	%	%	%							
PCI Express - Firmware												
Ethernet (1G, 10G, 25G, 100G) - Controller												
Ethernet (1G, 10G, 25G, 100G) - <i>Firmware</i>												
USB (1.0, 2.0, 3.0) - Controller												
USB (1.0, 2.0, 3.0) - <i>Firmware</i>												
SATA - Controller												
SATA - Firmware												
Thunderbolt - Controller												
Thunderbolt - Firmware												
Firewire - Controller												
Firewire - Firmware												
Memory - DDR3 and DDR4 - Controller												
Memory - DDR3 and DDR4 - Firmware												
ZigBee - Controller												
ZigBee - <i>Firmware</i>												
Bluetooth - Controller												
Bluetooth - <i>Firmware</i>												
802.11 - Controller												
802.11 - <i>Firmwar</i> e												
Other - Controller [Write in]												
Other - Firmware [Write in]												
Comments:	Comments:											
	BUSIN	ESS CONFID	ENTIAL - Pe		(d) of the De	fense Produc	ction Act					

CORPORATE LEVEL RESPONSE

Section 6b:

Embedded Integrated Circuit Bit Cell and Memory Compiler Intellectual Property Sources

For your analog, Application Specific Integrated Circuit and Field Programmable Gate Array products, state the percentage of embedded Integrated Circuit bit cell and memory compiler intellectual property used by your organization in 2016 that was 1) produced internally at company facilities located in the U.S. and at Non-U.S. company locations; 2) licensed from U.S. companies, and 3) licensed from non-U.S. companies. Secondly, identify the top three non- U.S. suppliers and countries that were sources of bit cell and memory compiler intellectual property used in products manufactured by your company in 2016. Select all that apply -- A blank response is counted as "No Capability."

Company Produced / L	Country and Sources of Bit Cell, Memory Compiler IP										
Type of Memory Device IP	Internally Produced at Company Locations in U.S.	Internally Produced at Company Locations Outside the U.S.	Licensed from U.S. Companies	Licensed from non- U.S. Companies	Total (must add up to 100%)	Supplier #1 Name	Country #1	Supplier #2 Name	Country #2	Supplier #3 Name	Country #3
Embedded EEPROM – Bit Cell	%	%	%	%	%						
Embedded EEPROM – Memory Compiler											
Embedded FLASH – Bit Cell											
Embedded FLASH – Memory Compiler											
Embedded SRAM – Bit Cell											
Embedded SRAM – Memory Compiler											
Embedded DRAM – Bit Cell											
Embedded DRAM – Memory Compiler											
Embedded Other – Bit Cell [Write in]											
Embedded Other – Memory [Write in]											
Comments:											

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CORPORATE LEVEL RESPONSE Performance of Production Functions for the Design of Integrated Circuits

Section 7a

Answer the questions on this page ONLY if your organization operates design facilities in the United States to produce Integrated Circuit products. If your organization does not operate design facilities in the United States, proceed to Section 7b.

Identify practices from the list below that reflect; 1) your organization's business methods in regard to execution of the eight design functions listed along the top of this page; 2) its practices and plans on outsourcing Integrated Circuit design.

				Integrated	Circuit Design	Functions			
Respond to All Questions	Analog	Digital	RTL Design*	Synthesis**	Physical Layout***	Functional Verification***	Simulation	Test Vector Generation****	Other (Specify Here)
In 2016 performed the following Integrated Circuit Design Steps at facilities in the United States that it owns and operates:	Yes/No/Not Applicable								
Did not design at its own U.S. facilities, but contracted with other U.Sbased organizations to perform the design tasks at their U.S. facilities.	Yes/No/Not Applicable								
For the 2017-2021, my organization expects to retain capability to perform the following Integrated Circuit design steps at facilities in the United States that it owns and operates.	Yes/No/Not Applicable								
 For 2017-2021 period, my organization will secure other U.Sbased vendors to complete these design steps at their facilities in the United States. 	Yes/No/Not Applicable								
Anticipates that the organization's capabilities to perform the following the eight design steps facilities in the United States will:	Increase/Decrease/ No Change								
Expects that its use of outsourcing in 2017-2021 will:	Increase/Decrease/ No Change								
7. In 2016, my organization outsourced the following Integrated Circuit design steps to facilities located outside of the United States that it owns and operates:	Yes/No/Unknown								
The following Integrated Circuit design steps were out-sourced in 2016 to non-U.S. companies operating at non-U.S. locations:	Yes/No/Unknown								
The three primary reasons why my organization outsources Integrated Circuit design steps to non-U's locations are:		Reason # 1			Reason #2			Reason #3	
10. In the space provided, identify the top five countries to which your		Country #1			Country #2			Country #3	
organization outsources Integrated Circuit design:					Country #4			Country #5	
Comments:			•		•	•			

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	Reasons for Outsou	rcing
ariff avoidance	Lower costs	Joint venture
roximity to customer	Market access	Availability of skilled labor
Sovernment subsidies	Production efficiency	Other

CORPORATE LEVEL RESPONSE

Section 7b Performance of Production Functions for the Manufacture of Integrated Circuits

Answer the questions on this page ONLY if your organization operates manufacturing facilities in the United States to produce Integrated Circuit products. If your organization does not operate manufacturing facilities in the United States, proceed to Section 7c.

Identify practices from the list below that reflect; 1) your organization's business methods in regard to execution of the eight manufacturing functions listed along the top of this page; 2) its practices and plans on outsourcing Integrated Circuit manufacturing.

				Integrated Circ	cuit Manufactur	ing Eunstions			
				Integrated Circ	Cuit Manuraciui	ing runctions			
Respond to All Questions	Mask Making	Wafer Manufacturing (Front End)	Wafer Manufacturing (Back End)	E-Test	Wafer Sorting	Dicing	Packaging	Final Test & Inspection	Other (Specify Here)
In 2016 performed the following Integrated Circuit Manufacturing Steps at facilities in the United States that it owns and operates:	Yes/No/Not Applicable	_							
Did not manufacture at its own U.S. facilities, but contracted with other U.S based organizations to perform the manufacturing tasks at their U.S. facilities.	Yes/No/Not Applicable								
For the 2017-2021, my organization expects to retain capability to perform the following Integrated Circuit manufacturing steps at facilities in the United States that it owns and operates.	Yes/No/Not Applicable								
For 2017-2021 period, my organization will secure other U.Sbased vendors to complete these manufacturing steps at their facilities in the United States.	Yes/No/Not Applicable								
Anticipates that the organization's capabilities to perform the following the eight manufacturing steps facilities in the United States will:	Increase/Decrease/ No Change								
6. Expects that its use of outsourcing in 2017-2021 will:	Increase/Decrease/ No Change								
In 2016, my organization outsourced the following Integrated Circuit manufacturing steps to facilities located outside of the United States that it owns and operates:	Yes/No/Unknown								
The following Integrated Circuit manufacturing steps were out-sourced in 2016 to non-U.S. companies operating at non-U.S. locations:	Yes/No/Unknown								
The three primary reasons why my organization outsources Integrated Circuit manufacturing steps to non-U's locations are:		Reason #1			Reason #2			Reason #3	
10. In the space provided, identify the top five countries to which your		Country #1	-		Country #2			Country #3	
organization outsources Integrated Circuit manufacturing:					Country #4			Country #5	
Comments:									
BUSINI	I ESS CONFIDENT	IAL - Per Secti	on 705(d) of the	e Defense Prod	luction Act				

< Reasons for Outsourcing										
Tariff avoidance	Lower costs	Joint venture								
Proximity to customer	Market access	Availability of skilled labor								
Government subsidies	Production efficiency	Other								

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CORPORATE LEVEL RESPONSE

														CORPO	RATE L	EVEL R	RESPON	ISE																	Ш
Specify the characteristics of the Int												na Stens																							
Specify the characteristics of the Integrated Circuit products for which your organization outsources Design and/or Manufacturing Steps. If your organization does not outsource Integrated Circuit design or manufacturing facilities in the United States, proceed to Section 8. Outsourced Design - by Device Type, Material, & Circuit Technology Node																																			
			Con	a bilita r			1							ly A bla r Materia			counted	as "No C	Capability	/")	1				ivarris	Took		n. No	do Inc		24272	,	_		
			Capa _	ability	1	Ι		1	I	1	1	Semico	naucto	r Materia	ii rypes	1	1	I	I		1			1	Ircun	recni	nolog	y No	je įna	anome	eters	'	$\overline{}$		-
Device Types	Conventional IC Products	Radiation Tolerant	Radiation Hardened	Neutron Hardened	Single-Event Effects Resistant - Destructive	Single-Event Effects Resistant - Non- Destructive	Amorphous Silicon	Bulk Silicon	Silicon on Insulator	Silicon Germanium	Silicon on Sapphire	Silicon Carbide	Aluminum Gallium Arsenide	Gallium Arsenide	Gallium Nitride	Indium Phosphate	Antimonides	Organic Technologies	Carbon Based Technologies (e.g., nanotubes)	Superconducting Materials	10,000 - 6,000	3,000 - <6,000	1,500 - <3,000	800 - <1,000	500 - <800	350 - <500	250 - <350	130 - <180	90 - <130	96 30	45 - <60	32 - <45	14 - <22	7 - <10	/>
Analog/Linear Technologies	Design																																		
Digital Logic Technologies	Manufacti	ure																																	
Digital Signal Processors	Both																																		
Field Programmable Gate Arrays	Neither																																		
One-time, Electrically Programmable Gate Arrays																												\perp		Ш					
Mask Programmable Gate Arrays																														Ш					
Structured ASICs [a.k.a. Structured Arrays; Platform ASICs]																														Ш					
Standard Cell ASICs [a.k.a. cell-based ASICs]																												\perp		\sqcup	_	ᆚ	╙	igsqcut	╛
Custom ASICs																														\sqcup		┵	┸		╛
MMIC** Technologies																														\sqcup		┵	┸		╝
Mixed Signal Technologies																														\sqcup		┵	┸		╛
Processors																												\perp	Ш	$\perp \perp$			┸		
Nonvolatile Memory																												<u> </u>		$\perp \perp$			\perp		
3-D Nonvolatile Memory																												<u> </u>		$\perp \perp$			\perp		
SRAM																												\perp	Ш	$\perp \perp$			┸		
DRAM - DDR3																														Ш					
DRAM - DDR4																												<u> </u>		$\perp \perp$			\perp		
IR*-Focal Plane Arrays																													Ш	$\perp \downarrow$			\perp	Ш	
Anti-Tamper Technology																													Ш	$\perp \downarrow$		\perp	\perp	Ш	
Display Electronics																													Ш	$\perp \perp$	\perp		\perp	Ш	
MEMS Technologies																													Ш	Ш				Ш	
Optical/Photonic Technologies																												\perp		Ш				Ш	
RF Technologies																														$\perp \perp$			\perp	Ш	
Other: [Write In]																														Ш		\perp			
Comments:																																			
								В	USINES	S CONF	IDENTI	AL - Per	Section	705(d)	of the D	efense l	Product	ion Act																	J

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	C	ORPORATE LE	VEL RESPONSE		
Section 8a: National Sec	urity Requireme	nts - The Trust	ed Access Prograi	n	
 Does your organization have i Circuit products in a trusted* env Defense (DOD) standards for the 	rironment located	in the United St			Design/Manufacture/Both/Not Applicable
2. Has your organization been co	ertified by DOD's	Trusted Access	Program Office at t	he Defense	
Microelectronics Activity (DMEA)) as a 'trusted' su	pplier of Integrat	ted Circuit products	?	Yes/No/Not Applicable
3. Is your organization planning to Defense Microelectronics Activity		•			Yes/No/Unknown
4. How does your organization v securing accreditation through D				es incurred for	Favorably/Unfavorably/No opinion
5. Is your organization familiar w which do you assess most favora					Unfamiliar/Split Manufacturing/Tiers of Trust/Trust by Design
6. If your organization has recen identify the affected facility by na		-	reason for your org		
Name:			Address:		
Explanation:					
7. If you answered "Yes" to Quebeen awarded, (2) the facilities for that facility.		•		~	` '
Facility Name(s)	City	State	Awarded Certification	Seeking Certification	Business Activity
			Yes/No	Yes/No	Design
					Manufacture
					Package, Test, Assembly
Comments:					
* "Trusted" refers to certification from the D	efense Microelectronic	cs Activity's Trusted A	Accreditation Program to d	esign or manufacture I	ntegrated Circuits.
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CORPORATE LEVEL RESPONSE

Section 8b National Security Requirements - Outlook on Future Capability to Supply Integrated Circuit Products
For each of the Integrated Circuit devices listed, indicate 1) how your organization's ability to design and/or manufacture at its United States facilities may change in the next five years. 2) State the primary factor contributing to this change (if applicable); and 3) Identify the types of customers that would be affected by this change.

affected by this change.						
		(Select all that a	pply A blank resp	oonse is counted as	"No Capability")	
Device Types	Inte	egrated Circuit Des		Integra	ted Circuit Manufa	
	Future Capability	Primary Factor	Types of Affected Customers	Future Capability	Primary Factor	Types of Affected Customers
Analog/Linear Technologies						
Digital Logic Technologies	Increase	Labor costs	Commercial (COTS stan	ndard Products)		
Digital Signal Processors	Decrease	Cost of Modernization	Commercial(Custom Pro	oducts)		
Field Programmable Gate Arrays	Cease	Low order volume	Industrial (COTS standa	ard Products)		
One-time, Electrically Programmable Gate Arrays	No Change	,	Industrial(Custom Produ	ucts)		
Mask Programmable Gate Arrays	N/A	Meeting DOD Requirements	U.S. Government Agend	cies - excluding DOD (Cu	stom Products)	
Structured ASICs [a.k.a. Structured Arrays; Platform ASICs]		Regulations	DOD (Custom Products))		
Standard Cell ASICs [a.k.a. cell-based ASICs]		Technology lag	DOD (COTS standard P	Products)		
Custom ASICs		Low Profitability	DOD (Custom Products))		
MMIC** Technologies		Trusted Certification Costs	U.S. Government Agend	cies - excluding DOD CO	TS standard Products)	
Mixed Signal Technologies		Rising Commercial Orders				
Processors		Rising US Government Orders				
Nonvolatile Memory		Design Difficulty				
3-D Nonvolatile Memory						
SRAM						
DRAM - DDR3						
DRAM - DDR4						
IR*-Focal Plane Arrays						
Anti-Tamper Technology						
Display Electronics						
MEMS Technologies						
Optical/Photonic Technologies						
RF Technologies						
Other [Write In]						
Comments:						
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CORPORATE LEVEL RESPO

Section 9:			nent Supplie																
For each of the listed processes, identify those used by y three. A blank response will be counted as "no capability	our organiza ."	tion by 1) W	riting in princ	ipal equipment	type 2) Prim	nary practice	for maintain	ing equipme	nt and 3) yo	ur organizati	on's three pr	imary suppli	ers of that ed	quipment. If	you only have	e one suppli	er, enter "No	one" for supp	liers two and
										quipment S By Process									
							(Selec	t all that app		response is		"No Capabil	ity")						
Integrated Circuit Manufacturing Processes - Front to Back	Type of Equipment #1	Type of Equipment #2	Type of Equipment #3	Primary Company Practice - Equipment Maintenance Performed By:	Equipment Supplier #1	City	State	Country	Single or Sole Source Suppler	Equipment Supplier #2	City	State	Country	Single or Sole Source Suppler	Equipment Supplier #3	City	State	Country	Single or Sole Source Suppler
Wet Wafer Cleaning	Write In			Company employ	ees														
Piranha solution				Manufacturer															
RCA clean				OEM Distributor															
Photolithography				Third-Party Contra	actor														
Ion implantation																			
Dry etching																			
Wet etching																			
Plasma strip/Ashing																			
Thermal treatments Rapid thermal anneal																			
Furnace anneals			İ				İ											İ	
Furnace Thermal oxidation																			
Rapid thermal oxidation																			
Epitaxy																			
Chemical vapor deposition (CVD)																			
Plasma enhanced chemical vapor deposition (PECVD)																			
Rapid thermal chemical vapor deposition																			
Physical vapor deposition (PVD)																			
Molecular beam epitaxy (MBE)																			
Electrochemical deposition (ECD)																			
Chemical-mechanical planarization (CMP)																			
Inline monitor testing at wafer level [interstitial/ silver /kerf structures]																			
Wafer bumping (flip chip products only)																			
Through silicon via (TSV), back side thinning and backside metal redistribution [if a 3-D chip]																			
Wafer functional test (testing of design structures)																			
Wafer backgrinding (Smartcard, PCMCIA cards, other applications)																			
Die preparation Wafer mounting / Tape																			
Die cutting/dicing																			
IC packaging Die attachment/bonding																			
IC bonding Wire bonding (if wirebond product)																			
Thermosonic bonding																			
Wafer bonding (if a wafer level bonded assembly)																			
Tape Automated Bonding (TAB)																			
IC encapsulation Baking																			
Plating																			
Laser marking																			
Trim and form																			
IC testing																			
Comments:			· · ·	511	CINECO CO	UEIDENT' A	Dan Carati	705(-1)	23	- Dandard	- 1-1								
				BUS	SINESS COM	NEIDENTIA	L - Per Secti	on /U5(d) o	the Detens	e Productio	n ACt								

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				FACILITY	LEVEL RE	SPONSE				
Section 1 A.	Indicate th	Employment be primary Integrated Cir actors at this facililty:							Design/Manufacture/F Assembly	•
		total number of full time ed ot double count personnel					J.S./domestic	operations b	y labor type for cale	ndar years 2013-
			Schedule:		,		alendar Yea	ar/Fiscal Ye	ar	
_						2013	2014	2015	2016	
B.	1	FTE Employees								
	2	FTE Contractors								
	3	Number of US Citizens								
	4	Number of non-US Citi					11.0			
		o five countries (other the number of each type of		en card hol	der associat	ted with ead	ch country.			
		Country		H-1B	H-2B	F	-1			al (Auto Sum)
C.				#	#			7	#	#
О.										
	Circuit pro	duct manufacturing (fab	rication). Bl	lanks will be	interpreted	l as meanin	g that there	are no pers	sonnel on site at th	is facility
	performing Occup	the listed job function.	Number of Staff	Occup	eational Cate	egory -	Number of Staff		pational Category - acture of Integrated	Number of
	performing Occup Design	g the listed job function. pational Category - of Integrated Circuits	Number of	Occup Manufa	pational Cate acture of Inte Circuits	egory -	Number of	Manufa	pational Category - acture of Integrated Circuits	Number of
	Occup Design Silicon Design	g the listed job function. pational Category - of Integrated Circuits	Number of	Occup Manufa Environmenta	pational Cate acture of Inte Circuits al Engineering	egory -	Number of	Manufa Engineering N	pational Category - acture of Integrated Circuits Manager	Number of
	performing Occup Design	g the listed job function. pational Category - of Integrated Circuits	Number of	Occup Manufa Environmenta Safety Engine	pational Cate acture of Inte Circuits al Engineering eer	egory - egrated	Number of	Manufa Engineering Manufacturing	pational Category - acture of Integrated Circuits Manager g Manager	Number o
	Occup Design Silicon Desig Researcher Quality Engir	g the listed job function. pational Category - of Integrated Circuits	Number of	Occup Manufa Environmenta Safety Engine Planning/Proc	pational Cate acture of Inte Circuits al Engineering	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician	Number o
	Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V	g the listed job function. pational Category - of Integrated Circuits an Architect	Number of	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician	pational Cate acture of Inte Circuits al Engineering eer	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manage	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician	Number o
C.	Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V	g the listed job function. pational Category - of Integrated Circuits In Architect Integrated Circuits Integra	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician	pational Cate acture of Inte Circuits al Engineering eer curement/Supp	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer	Number o
C.	Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V	g the listed job function. pational Category - of Integrated Circuits In Architect Pational Category - Of Integrated Circuits In	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engi	pational Cate acture of Inte Circuits al Engineering eer curement/Supp	egory - egrated	Number of	Manufa Engineering M Manufacturing Facilities Engi Shift Manager Failure Analys Integration Er	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer	Number o
C.	Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engir	g the listed job function. pational Category - of Integrated Circuits gn Architect neers 'alidation Engineer validation Engineer neer	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engine	pational Cate acture of Inte Circuits al Engineering eer curement/Supp neer/Technicia	egory - egrated	Number of	Manufa Engineering M Manufacturing Facilities Engi Shift Manager Failure Analys Integration Er	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician	Number o
C.	Performing Occup Design Silicon Desig Researcher Quality Engin Pre Silicon V Post Silicon V Layout Engin Debug Engin	g the listed job function. pational Category - of Integrated Circuits In Architect Integrated Circuits Integra	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering Manufacturing Facilities Engi Shift Manager Failure Analys Integration Er Automation E	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number o
C.	Occup Design Silicon Desig Researcher Quality Engin Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er	g the listed job function. pational Category - of Integrated Circuits In Architect Integrated Circuits Integra	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Manufacturing	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number o
C.	Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In In In In In In In In In In In In I	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engine Manufacturing Equipment Er	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number o
C.	Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E Integration E	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In In In In In In In In In In In In I	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engine Manufacturing Equipment Er	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number of
C.	Performing Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E Integration E CAD Engine Thermal Eng Mechanical E	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In Architect In In In In In In In In In In In In In I	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engine Manufacturing Equipment Er	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number o
C.	Performing Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E Integration E CAD Engine Thermal Eng Mechanical E Packaging E	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In Architect In In In In In In In In In In In In In I	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engine Manufacturing Equipment Er	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number of
C.	Performing Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E Integration E CAD Engine Thermal Eng Mechanical E	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In Architect In In In In In In In In In In In In In I	Number of Staff	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engine Manufacturing Equipment Er	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number o
C.	Performing Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E Integration E CAD Engine Thermal Eng Mechanical E Packaging E Program Mar	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In Architect In In In In In In In In In In In In In I	Number of Staff Type of In	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engine Manufacturing Equipment Er	pational Cate acture of Inte acture	egory - egrated	Number of	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration En Automation E Factory Mana	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ngineer/Technician	Number o Staff
D.	Performing Occup Design Silicon Desig Researcher Quality Engir Pre Silicon V Post Silicon V Layout Engin Debug Engin Electronic Er RF/Analog E Integration E CAD Engine Thermal Eng Mechanical E Packaging E Program Mar State 1) the working at t percentage projected to	g the listed job function. pational Category - of Integrated Circuits In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In Architect In In Architect In In Architect In In Architect In In Architect In In In Architect In In In Architect In In In In In In In In In In In In In I	Number of Staff Type of In	Occup Manufa Environmenta Safety Engine Planning/Proc Statistician Process Engin Product Engin Reticle Engin Manufacturing Equipment Er Industrial Eng	pational Cate acture of Inte acture	egory - egrated	Number of Staff	Manufa Engineering N Manufacturing Facilities Engi Shift Manager Failure Analys Integration Er Automation E Factory Mana Yield Enginee	pational Category - acture of Integrated Circuits Manager g Manager ineering/Technician r sis Engineer ngineer/Technician ager er % Projected to leave or retire	Number of Staff

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		CORPOR	ATE LEVEL RES	SPONSE			
Section 11 For years 2 remain und	2013-2016 provide your organization's U	.S. and non-U.S. sa	les information. F	For 2017, project v	whether your sal	es will increase, de	ecrease or
	F	eporting Schedule:		Cale	endar Year/Fisca	l Year	
Reco	rd \$ in Thousands, e.g. \$12,000.00 = surve	ey input of \$12	2013	2014	2015	2016	2017*
A.	Total Sales, all Customers (in \$)						
B.	Total IC-Related Sales, all Customers U.S./	Non-U.S. (in \$)					
C.	Total U.S. IC-Related Sales - as a % of B						
D.	Total Non-U.S. IC-Related Sales - as a % o	f B					
E.	Direct sales of Custom IC Products (including to U.S. Government customers (in \$)	ng design services)					
F.	Is your organization dependent of U.S.	Government sales f	or its ongoing via	bility?			Yes/No
	Identify your organization's 1) top five of primary type of IC product supplied (IC product; and 3) indicate whether the product;	designs or fabricate oducts were supplie	ed product) sold to d under DMEA To	them and the es	timated revenue tification.		
G.	Commercial End Customer Name	Country	Estimated 2016 Revenue - All Product Sales		oduct Type n Revenue)	Estimated 2016 Revenue -Primary Product	DMEA Trusted Program
				Drop-Down of 23 Pro	oduct Classes		Yes/No
	Identify your organization's 1) top five L 2) state the primary type of IC product sthe primary product; and 3) indicate wh	supplied (IC designs	or fabricated provere supplied und	duct) sold to then ler DMEA Trusted	n and the estima d Access certifica	ited revenue for 20 ation.	
	тор 3 о.з.	Sovernment Custo		II Floudets (Noi	I-CO 13) by Nev		51454
Н.	Government End Customer Name	Federal Agency	Estimated 2016 Revenue - All Product Sales		oduct Type n Revenue)	Estimated 2016 Revenue -Primary Product	DMEA Trusted Program
				Drop-Down of 23 Pro	oduct Classes		Yes/No
	Comments:						
exempt fro	e of financial information is required f om Freedom of Information Act (FOIA on's financial data.						
	BUSINESS C	ONFIDENTIAL - Pe	r Section 705(d)	of the Defense F	Production Act		

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	CORPORATE LEVEL RESPONSE	

Section 12: Financials

Provide the following Income Statement and Balance Sheet financial line items for your organization for years 2013-2016 below. Furnish full-year estimates for 2016.

	,								
	Reporting Schedule:	(Fiscal Year/Calendar Year)							
In	come Statement (Select Line Items)	Record \$ in Thousands, e.g. \$12,000.00 = survey input of \$12							
111	come Statement (Select Line items)	2013	2014	2015	2016				
A.	Net Sales (and other revenue)								
B.	Cost of Goods Sold								
C.	Total Operating Income (Loss)								
D.	Earnings Before Interest and Taxes								
E.	Net Income								
	Source of Balance Sheet Items:		(Corporate/Whole Organization)						
	Reporting Schedule:	(Fiscal Year/Calendar Year)							
	Balance Sheet (Select Line Items)	Record \$ in Thousands, e.g. \$12,000.00 = survey input of \$12							
	Balance Sheet (Select Line Items)	2013	2014	2015	2016				
A.	Cash								
B.	Inventories								
C.	Current Assets								
D.	Total Assets								
E.	Current Liabilities								
F.	Total Liabilities								
Comments:									

Disclosure of financial information is required for both public and private companies. All financial data is treated as Business Proprietary and exempt from Freedom of Information Act (FOIA) requests. Providing BIS with financial information will not result in the public release of you organization's financial data.

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	Reporting of Significant One-Time Events
Year	Instruction: Provide an explanation of any significant one-time events that would skew assessments of the economic performance of your organization.
2013	
2014	
2015	
2016	

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Section '	13: Acquisi	tions, Divestitures, Mergers and Joir		ATE LEVEL RESP	ONSE							
		Acquisitions, Divestitures, and Mergers										
	How many	Integrated Circuit-related acquisitions, dive	stitures and mergers has your organize	zation been party to s	ince 2013?	If none, a "0" must be	e placed in the box.					
	Identify you description	Identify your organization's five most recent Integrated Circuit-related acquisitions, divestitures and mergers, going back no more than five years. Identify the primary objective of each event listed and provide a										
		Organization Name	Type of Activity	Country	Year	Primary Objective	Explain (optional					
A.	1		Acquisition									
	2		Divestiture									
	3		Merger									
	4											
	5											
	Joint Ventures											
	How many Integrated Circuit-related joint ventures does your organization currently participate in?											
	Identify you	Identify your organization's current Integrated Circuit-related joint venture relationships, including public/private R&D partnerships. Select the primary objective of the joint venture and provide a description.										
		Organization Name	3	Country	Year	Primary Objective	Explain (optional					
В.	1											
	2											
	3											
	4											
	5											
		Have any non-U.S. governments (including sovereign wealth funds) invested, directly or indirectly, in your organization - and collectively control five percent or more of stockholder voting shares? Yes - Directly/Yes - Indirectly/No										
C.	1	If you answered "yes" explain in the space	below the nature of the investment a									
	Co	mments:										
			BUSINESS CONFIDENTIAL - Pe	r Section 705(d) o	f the Defense Proc	luction Act						
			CO 200 COM IDENTIAL - 1 6	. 555tion 755(u) 0	Deterior i ioc							

Primary Objective Dropdown					
Access to government contracts	Market Access				
Access to intellectual property	R&D access/coordination				
Bankruptcy restructuring	Reduce costs				
Broaden customer base	Regulatory				
Develop new capabilities	Tax-related				
Expand Product Lines	Vertical integration				
	Other objective (Explain)				

< Primary Objective Dropdown					
Cost Reduction Market Access					
Access to technology	Product Improvements				
Other	Risk sharing				

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Section 14: Capital Exper	nditures									
		CORPORA	TE LEVEL	RESPONSE						
A. Did your organiz	zation track capital expenditure financials be	etween 2013 and	If not, enter "0" in section B							
(Capital Expenditure Reporting Schedule:					Calendar Yea	r/Fiscal Yea	ar		
	Capital Expenditure Category			Red	cord \$ in Th	ousands, e.g. \$1	2,000.00 = s	urvey input of \$	12	
	Capital Expericiture Category		2	013	2	014	2	2015	2	2016
			U.S.	Non-U.S.	U.S.	Non-U.S.	U.S.	Non-U.S.	U.S.	Non-U.S.
	al Capital Expenditures									
R	Total Integrated Circuit-related Capital Expenditures									
3 Mac	chinery and Equipment [as a % of row 1]									
·	Computers, Software [as a % of row 1]									
	Land, Buildings, and Leasehold Improvements [as a % of row 1]									
	er [Write In]									
Lines 1 through	4 must total 100%		0%		0%		0%			0%
From 2013-2010	rom 2013-2016, what was the most significant factor in dictating your organiz			xpenditures?						
C. 110111 2013 2011	Explain:		-	•						
Rank your organ	nization's top 3 capital expenditure priorities	for 2013-2016, anticipa	ated prioritie	s for 2017-2021	, and provi	de a brief descr	iption.			
Priority		2013	2013-2016 2017-2021		2021			Description		
	place old machinery and equipment		1		1					
2 Impr	rove productivity		2	2						
1).	and capacity	:	3	3						
The state of the s	new capability			1						
	rade technology									
6 Mee	et specific customer requirements									
7 Othe	er [Write In]									
	Comments:			•		•				
	BUSINESS	CONFIDENTIAL - Per	Section 705	(d) of the Defe	ense Produ	ction Act				

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Section 1	5: Resear	ch & Development						
		CORPORATE LEVEL	RESPONSE	1				
A.	Does your organization perform Research and Development (R&D)? Yes/No If not, proceed to section 16							
In Questio	on C, identi	d your organization's total R&D dollar expenditures for years 2013- ify your organization's R&D funding sources, by percent of total R&I unding sources reported (section C) can exceed total expenditures	O dollars sourced.	for a given year.				
		Reporting Schedule:		Ca	lendar Year/Fiscal Y	ear		
			Record \$ in	Thousands, e.g. \$	12,000.00 = survey	input of \$12		
			2013	2014	2015	2016		
	1	Total R&D Expenditures	\$					
B.	2	Basic Research (as a percent of B1)	%					
	3	Applied Research (as a percent of B1)	%					
	4	Product/Process Development (as a percent of B1)	%					
	5	Total of 2 - 4 (must equal 100%)	0%	0%	0%	0%		
			Record \$ in Thousands, e.g. \$12,000.00 = survey input of \$12					
			2013	2014	2015	2016		
	1	Total R&D Funding Sources	\$					
	2	Parent Company (Internal)	%					
C.	3	Total Federal Government	%					
	4	State and Local Government	%					
	5	U.S. Private Entity [includes industry, universities]	%					
	6	Foreign Investors [includes industry, governments]	%					
	8	Other (specify here)	%					
	9	Total of 2 - 8 (must equal 100%)	0%	0%	0%	0%		
	1) Report the percentages of your organization's total annual R&D expenditures for supporting Integrated Circuit product design and manufacturing activity performed in U.S. and Non-U.S. locations for 2013-2016							
D.		R&D Expenditures For Integrated (Corporate or Integrate						
Б.	Total Into	grated Circuit-Related R&D Expenditures	2013	2014	2015	2016		
	Total litte	Percent Performed at All U.S. Locations	<u>2013</u> %	2014	2010	2010		
		Percent Performed at All Non-U.S. Locations	% %					
		Total Integrated Circuit R&D Expenditures						
			Ψ	<u> </u>	<u> </u>	<u> </u>		
		Comments:						
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Data Confirmation

Total 2016 R&D

Expenditures

None

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Section 16	6a - Export Re	gulation &	Trade Issues: Regulat		PORATE LEVEL	DESPONSE				
				COM	'UKATE LEVEL			Yes/No		
A.	Identif	v the Integra	ted Circuit-related products	s that your organization	n exports:	IC Designs		Yes/No		
						Partially Built ICs Complete IC Prod		Yes/No		
			ort control system (Export A			rce Control List [CC	CL]), or	EAR/CCL	Yes/	/No
B.			s Regulations [ITAR]/U.S. M gn services and manufactu		for the export or in	tegrated Circuit-reid	ated products	ITAR/USML	Yes/	/No
	If you do not uti		port control licenses for Inte	grated Circuit -related	products or service	es, select "No" in th	ne box and	Traves	Yes/No	110
			export sales opportunities of					Lost Sales?*	Lost Export Sa	ales Estimate
C.			titors because of U.S. expo ar amount of lost export sal				/CCL	Yes/No	\$	
	*Loct Cales: Are	attributed to bi	indian written supply contract	to (not optimates) of a etc	ated dollar value that		USML	Yes/No	rmined that the Integr	
			inding, written supply contracts and or manufactured devices)				because a review or	export regulations deter	mined that the integra	ated Circuit-related
	State whether Lat right.	J.S. export co	ontrol regulations since 201	13 directly affected you	ur organization's Int	tegrated Circuit bus	siness in any of the	e ways listed below.	If "Yes," explain in t	he box provided
			Impact		Resp	oonse		Explai	nation	
	1		r organization's Integrated (nd development program	Circuit-related	Y	′/N				
						Z/CCL				
	2		e export of products or servi L or ITAR/USML related co		/USML oth	_				
					N/A					
					EAR/CCL					
D.			composition of specific Inte	ITAR/USML						
		related busin	ness lines		oth I/A					
					EAR/CCL					
	4 Located of	Located or r	relocated Integrated Circuit	t-related facilities	ITAR/	/USML				
	7	outside the	United States due to regula	atory burdens.		oth				
					N N	I/A				
	5	Integrated C	rganization's avoided buying Circuit-related products or s	services.	Y	//N				
	6		n-U.S. organizations to offe CL-free" Integrated Circuit-re		Y/N					
E.	State whether r	eforms in exp	port control regulations (EA	AR/CCL and ITAR/USI	ML) have affected y	your Integrated Circ	cuit business:			Yes/No
		dicating from	ted below, identify how refo the list provided how expo ume.							
					Impacts of Export	t Control Reforms	3			
	Techno	ology		Regul	latory Impacts			Range of Trading Companies	Number of Trading Countries	Business Volume
F.		.03)	Impact #1	Impac	:t #2	Impa	act #3			
	Microwave Monolithic Integrated Circuits		Reduced Paperwork	Wider business opportunities	Other #1			Increase	Increase	Increase
			Increased Paperwork	Fewer business opportunities				Decrease	Decrease	Decrease
	Transmit/Receiv	vo Modulos	Reduced Licensing Time	Removed some controls	Other # 2			No Change	No Change	No Change
	Transmittecen	ve iviodules	Increased Licensing Time	Added some controls				Other		
	Comments:									
			BUSINES	S CONFIDENTIAL -	Per Section 70	5(d) of the Defer	se Production	Act		

Previous Page Table of Contents Next Page Section 17a - Trade and Intellectual Property Issues From the list below, identify the methods your organization uses to transfer Integrated Circuit-related design and manufacturing intellectual property on a legal, authorized basis to U.S. and non-U.S. destinations. Non-U.S. Design IP or Manufacturing IP Methods US Location(s) Location(s) Licensing Intellectual Property Yes/No Yes/No Design IP Joint Ventures Manufacturing IP Research collaborations 3oth Α Participation in scientific/technical conferences Information provided to potential investors **Debt Financing** Non-Disclosure Agreements Other [Write in] 8 From the list below, identify the methods by which unauthorized transfers of your company's Integrated Circuit-related design and manufacturing intellectual property have occurred. If yes, identify the types of IP. Non-U.S. US Location(s) Methods Design IP or Manufacturing IP Location(s) Cyber security intrusions Yes/No Yes/No Design IP Planting staff in your company Manufacturing IP Physical break-ins at company facilities 3 Both Business partners **Dumpster Diving** 6 Former employees В **Employees** External IT System Contractors 8 9 Persons performing R&D with your company Company campus Wi-Fi Network Interceptions 10 11 Persons speaking to outside industry analysts/experts 12 Persons speaking with your bankers/financiers 13 Persons speaking with contractors and suppliers 14 Violation of Non-Disclosure Agreements 15 Other [Write in] Type of IP In the years 2013-2016, did your organization experience unauthorized transfers of Integrated Circuit-1 related design and/or manufacturing Intellectual Property? Design/Manufacturing/Both/Neither Design IP Manufacturing IP If "Yes," report the number of instances this occured for Design IP and Manufacturing IP? 2 Yes/No Country Country Does your company know the country location(s) of the most frequent perpetrators of the unauthorized transfers of your company's Integrated Circuit-related intellectual property? If 3 "Yes" identify the countries. Yes/No/Not Yes/No/Not CCL/EAR Was the intellectual property subject to any the following export control applicable applicable С 4 regulations: USML/ITAR U.S. Department of Defense Yes/No U.S. Department of Commerce U.S. Department of State 5 Did your organization report the incident(s) to the: Federal Bureau of Investigation State/Local police authorities U.S. Department of Energy Other [Write In] In the past five years has your organization experienced a loss of access to critical Integrated Circuit-Yes/No/Not applicable related Intellectual Property? Comments: BUSINESS CONFIDENTIAL - Per Section 705(d) of the Defense Production Act

OMB 0694-0119 ROCIS Submission Return to Table of Contents Next Pac revious Page Section 17b: Trade and Intellectual Property Issues CORPORATE LEVEL RESPONSE Identify all trade practices and requirements that your organization has encountered at any time since 2013 in countries where it currently conducts business or seeks to do business directly or indirectly through third parties. Then, identify up to three countries where these practices or requirements have been encountered and whether they persist to date. **Trade Practices** Persists Today? Country #2 Persists Today? Persists Today? Yes/No Country #1 Country #3 Yes Yes Yes Tariffs on the Integrated Circuit-related products and services that your organization sells National trade policy to phase out the use of Integrated Circuit-related products designed or Nο No Nο made outside of their country Threats to boycott your organization's products unless your organization allows substantial N/A N/A investment by entities from that country Manipulation of your organization's publicly traded stock as a consequence of refusing to transfer intellectual property or establish design and/or manufacturing operations in that country Denied timely access to the country's market Comments: Persists Today? Country #2 Persists Today? Country #3 Persists Today? **Conditional Trade Requirements** Yes/No Country #1 Yes Transfer of Integrated Circuit-related device intellectual property (trade secrets, patents, etc.) Yes Yes Transfer of Integrated Circuit-related manufacturing process intellectual property (trade secrets, No No No patents, etc.) N/A N/A Outsource design of Integrated Circuit-related products to their country Establish Integrated Circuit-related design operations in their country Outsource the manufacture of Integrated Circuit-related products to their country Establish Integrated Circuit-related manufacturing operations in their country

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Required investment/equity from non-US companies in order to maintain market access Mandatory joint ventures as means to achieve transfers on design and/or manufacturing

Comments:

intellectual property and know-how

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ction	18: Competitiveness		CORPORATE LEVE	I RESPONSE		
	5					
	Rank your organization's top five issues	affecting the	long-term competitiver	and provide an explanation.		
	Issue	2013-2016 2017-2021		Explanation (optional):		
	Aging equipment, facilities, or infrastruc	ture	1	1		
	Aging workforce		2	2		
	Competition - domestic		3	3		
	Competition - foreign		4	4		
	Counterfeit parts		5	5		
	Cybersecurity					
	Environmental regulations/remediation					
	Environmental regulations/remediation	non-U.S.				
	Export controls; ITAR/USML; EAR/CCL					
	Forced localization					
	Government acquisition processes					
	Government purchasing volatility					
	Government regulatory burden					
	Healthcare costs					
A.	Health and safety regulations					
	Imports					
	Industrial Espionage					
	Intellectual property/patent infringement	t				
	Labor availability/costs					
	Material input availability					
	Product obsolescence					
	Pension costs					
	Proximity to customers					
	Proximity to suppliers					
	R&D costs					
	Reduction in commercial demand					
	Reduction in USG demand					
	Taxes					
	Worker/skills retention					
	Other (specify)					
	Other	(specify)				
	Comments:					
	DUCINE	CONFIDE	AITIAL Day Cooting 7	05(d) of the Defense Pro	advetion Apt	

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Section	19: Cy	ber Security								
		Estimate your organization's spending on ph	ysical and cyber se	curity, in thousands	s of dollars, and sta	te the number of se	curity incidents you	r organization has r	ecorded in each yea	ar.
		Reporting Schedule:	December 11		0.00					
				sands, e.g. \$12,00)13		014	2	015	1 20	16*
A.			Incidents	Expenditures	Incidents	Expenditures	Incidents	Expenditures	Incidents	Expenditures
		1 Cyber Security	#	\$	#	\$	#	\$	#	\$
		2 Physical Security	#	\$	#	\$	#	\$	#	\$
		* Furnish full year estimates for 2016 if data			(DELEGY			(=1.15.		T
		Is your organization aware of Defense Feder Reported Cyber Incident Information?	ral Acquisition Regi	ulation Supplement	(DFARS) 252.204-	7009, Limitations on	the Use or Disclos	sure of Third-Party C	Contractor	Yes/No
_	1	http://www.acq.osd.mil/dpap/dars/dfars/h	tml/current/25220	4.htm						163/140
B.		Explain:		•						
	2	Who is responsible for administering your or								Dropdown
	3	Who is responsible for administering your or Is the computer or computer network that ho				tion (CSI) connected	to the Internet, eit	her directly or via an	n intermediary	Dropdown
		network or server?	acco your organiza	and the Commondant	Conomic mornia	(00.) 0000.00		nor anoony or via an	· intorriousary	
	1									Yes/No
	•	*This includes customer/client information, fi								
		manufacturing and production line information chain information.	in, paterit and trade	mark imormation, i	esearch and deven	opment information,	regulatory/complia	nice iniornation, and	a supplier/supply	
			2.2						External Cloud Service	Restrict/Prohibit/No/L
		Does your organization either restrict or proh Information (CSI) outside of the U.S.?	libit your external c	loud service or exte	rnai data storage p	provider(s) from stori	ng Commercially S	ensitive	Providers External Data Storage	known Restrict/Prohibit/No/L
	2	information (con) detailed of the c.c.							Providers	known
	2								External Cloud Service Providers	(% Entry Only)
		Estimate the percentage of your organization	n's Commercially S	ensitive Information	(CSI) that is stored	d with:			External Data Storage	
									Providers	(% Entry Only)
	3			Advanced				Identity and access		
		Does your organization use the following cloud-based securi		authentication (biometrics, tokens	<yes no=""></yes>	End-point protection	<yes no=""></yes>	Identity and access management	<yes no=""></yes>	
				etc.)						
		protocols?		Real-time						
				monitoring/analytics	<yes no=""></yes>	Threat intelligence	<yes no=""></yes>	Other (specify)	<yes no=""></yes>	
		Explain:								
C.		Does your organization have structured met types of Commercially Sensitive Information	<yes no="" not<="" td=""><td></td><td></td><td>Explain</td><td></td><td></td></yes>			Explain				
0.		types of Commercially Sensitive information	Applicable>							
		Customer/client information								
		Financial information and records								
		Human resources information/employee data	a							
		Information subject to export control regulation	ons (EAR and/or IT	AR)						
			<u> </u>							
	,	Intellectual property related information								
	4	Internal communications including negotiation plans, and/or corporate strategy	in points, merger ar	nd acquisition						
		Manufacturing and production line information	on							
		Patent and trademark information								
		Regulatory/compliance Information								
		Research and development (R&D) related in	formation							
		Supply chain and sourcing information								
		Other (specify)								
		Using the drop-down lists and free-text entrie	es helow indicate t	he type(s) and seve	rity of any cyberse	curity events that ha	ve occurred at this	organization from 2	013-2016	
		Event		sypo(s) and seve		ct Level	Frequency		in (incident and follo	ow-up)
	1	1 (Choose from Drop-Down) Severe # Write in 2 (Choose from Drop-Down) Moderate								.,
D.	2									
	3	(Choose from Drop-Down)				.ow				
	4	Other Cybersecurity Event		ecify)	N	one				
	5	Other Cybersecurity Event		ecify)	L					
		encourages recipients to report information of .gov/contact-us/field. CyWatch can be contact activity, number of people,	ted by phone at 85	5-292-3937 or e-ma	ail at CyWatch@ic	:.fbi.gov. When avail	able, each report s	ubmitted should inc	lude the date, time,	
Comn	nents:	activity, number of people,	ана туре от ецирпі	ioni useu ioi iile aci	uvity, the name of t	no submitting organi	zadon, and a desig	graded point of conta	201.	
COM	ents.	1					0.1			
			BUSINESS C	ONFIDENTIAL - Pe	er Section 705(d)	of the Defense Prod	duction Act			

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Section 20: Certification					
a false statement or representation to any department or agency	response to this questionnaire is complete and correct to the best of his/her knowledge. It is a criminal offense to willfully make y of the United States Government as to any matter within its jurisdiction (18 U.S.C.A. 1001 (1984 & SUPP. 1197)).				
Once this survey is complete, submit it via e-mail to: XXX@bis.c	doc.gov. Be sure to retain a copy for your records and to facilitate any necessary edits or clarifications.				
Organization Name					
Organization's Internet Address					
Name of Authorizing Official					
Title of Authorizing Official					
E-mail Address					
Phone Number and Extension					
Date Certified					
In the box below, provide any additional comments or any other	information you wish to include regarding this survey assessment.				
How many hours did it take to complete this survey?					
BUSINESS CONFIDENTIAL - Per Section 705(d) of the Defense Production Act					